

PRELIMINARY

Notice : This is not a final specification
Some parametric limits are subject to change.

MITSUBISHI SEMICONDUCTOR <GaAs MMIC>

MGFC5211

K-Band 2-Stage Power Amplifier

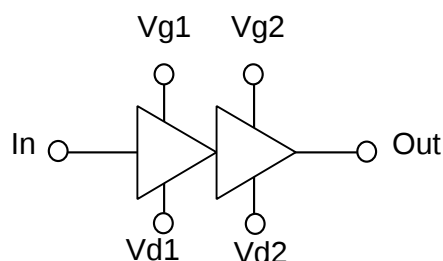
DESCRIPTION

The MGFC5211 is a GaAs MMIC chip especially designed for 21.2 ~ 23.6 GHz band High Power Amplifier (HPA) .

FEATURES

- RF frequency : 21.2 to 23.6 GHz
- Linear gain : ≥ 13 dB
- P1dB : ≥ 23 dBm
- DC power : $V_d = 5$ V, $I_{d1} + I_{d2} = 270$ mA

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Symbol	Parameter	Ratings	Units
Vd1, Vd2	Drain supply voltage	6	V
Vg1, Vg2	Gate supply voltage	-3 ~ 0.5	V
Id1	Drain current 1	120	mA
Id2	Drain current 2	240	mA
Pin	RF input power	16	dBm
Ta	Backside ambient temp.	-20 ~ +70	°C
Tstg	Storage temp.	-65 ~ +175	°C
Tmax	Maximum assembly temp.	+300	°C

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

Symbol	Parameter	Conditions	Limits			Units
			Min.	Typ.	Max.	
Gain	Gain	Vd = 5 V Id1 = 90 mA Id2 = 180 mA (RF off)	13.0			dB
VSWR in	Input VSWR				2.2	-
VSWR out	Output VSWR				2.2	-
P1dB	Output power at 1 dB compression point	f = 21.2, 23.6 GHz Single tone	23.0			dBm
IM3	Inter modulation level	f = 21.2, 23.6 GHz Two tone(10MHz off) Pout = 20 dBm	(22.0)			dBc



MITSUBISHI
ELECTRIC

as of July '98

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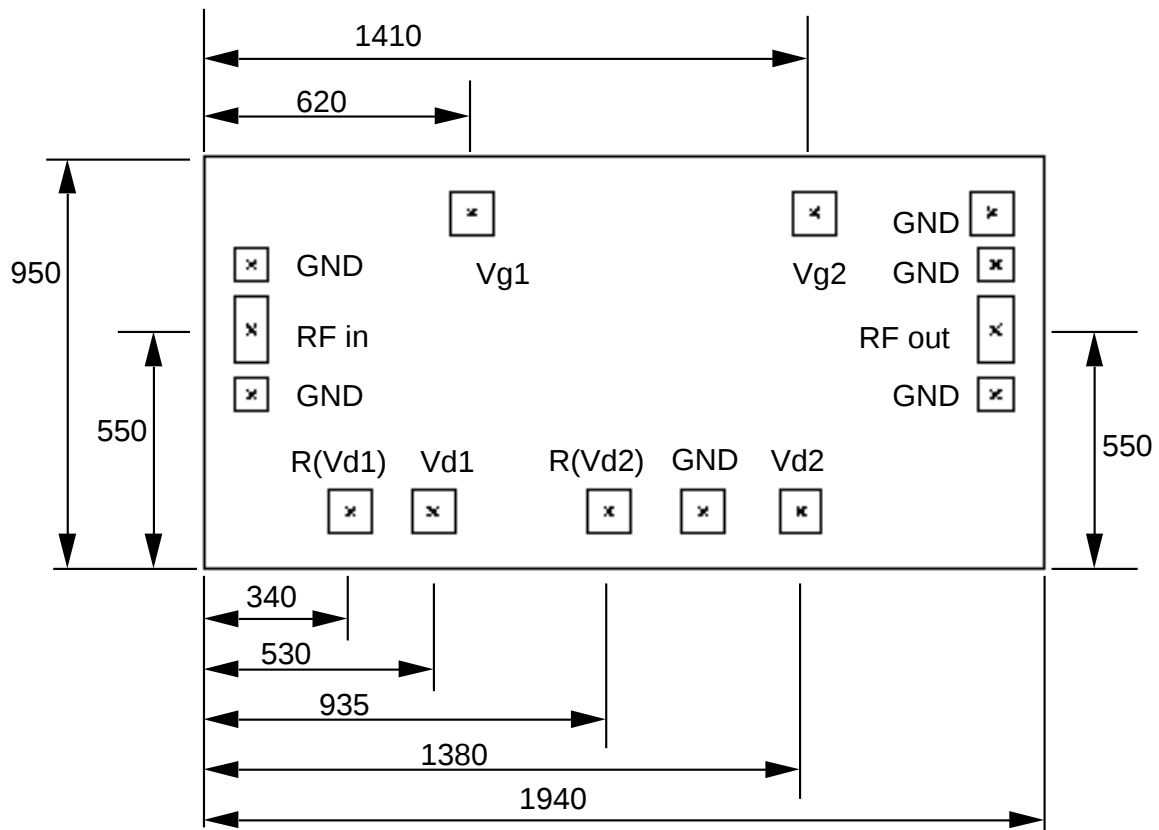
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DIE SIZE AND BOND PAD LOCATION(UNIT : μM)



X Dimention 1.94 mm

Y Dimention 0.95 mm



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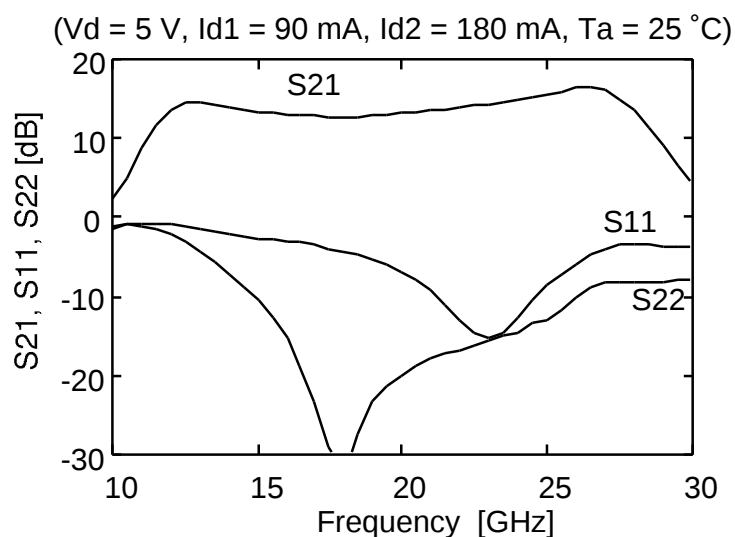
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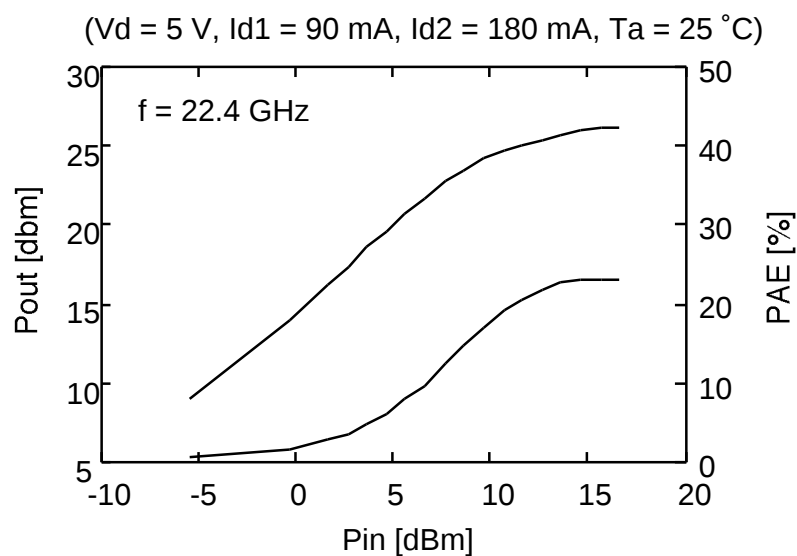
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TYPICAL CHARACTERISTICS

Small Signal Performances



Output Power Performances



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AN EXAMPLE OF TEST CIRCUIT

